DEC 2 7 2004

CERTIFICATE OF TR Applicant(s): Furquhar et a	ANSMISSION BY FAC I.	SIMILE (37 CFR 1.8)	Docket No. EN9-98-122US3
Application No. 09/781,730	Filing Date 2/12/2001	Examiner Goff II, John L.	Group Art Unit 1733
Invention: SEMICONDUC AND METHODS FOR FABR		HERMOSET-CONTAINING D	IELECTRIC MATERIAL
I hereby certify that this		nse to Interview Summary (1 pa	,
on 12/27/2004 (Date)		and Trademark Office (Fax. No	0. 703-872-9306
(2)			
	**************************************	Kim Dyriles (Typed or Printed Name of Person (\$\frac{1}{2}\text{(\$\frac{1}{2}\text{gnature})}\$	ski Signing Certificate)
		•	·
	Note: Each paper must hav	e its own certificate of mailing.	
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**DOCKET NO.: EN9-98-122US3** 

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Farquhar et al.

Examiner: Goff II, John L.

Serial No.: 09/781,730

Art Unit: 1733

Filed: 2/12/01

For: SEMICONDUCTOR DEVICE HAVING A THERMOSET-CONTAINING DIELECTRIC MATERIAL AND METHODS FOR FABRICATING THE SAME

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## Response to Interview Summary

Sir:

Applicant's Representative acknowledges that the Interview Summary mailed December 22, 2004 relating to the Interview on December 16, 2004 between the Examiner and Applicant's Representative is accurate.

Date: 12/17/2004

Jack P. Friedman

Registration No. 44,688

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09/781,730